NSN 5961-00-999-7088

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.547 inches

Overall Diameter:

1.281 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

85.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 25.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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